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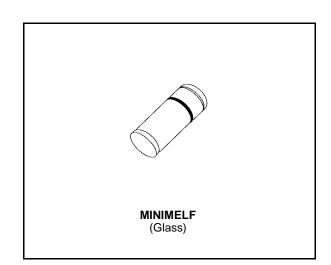
STMicroelectronics
TMMBAT48FILM

For any questions, you can email us directly: sales@integrated-circuit.com





SMALL SIGNAL SCHOTTKY DIODES



DESCRIPTION

General purpose, metal to silicon diodes featuring very low turn-on voltage and fast switching.

These devices have integrated protection against excessive voltage such as electrostatic discharges.

ABSOLUTE RATINGS (limiting values)

| Symbol | Parameter | TMMBAT47 | TMMBAT48 | Unit | | |
|------------------------------------|--|---|----------|------|---|--|
| V_{RRM} | Repetitive Peak Reverse Voltage | 20 | 40 | V | | |
| I _F | Forward Continuous Current | T _I = 25 °C | 35 | 350 | | |
| I _{FRM} | Repetitive Peak Fordward Current | $\begin{array}{l} t_p \leq 1s \\ \delta \leq 0.5 \end{array}$ | | Α | | |
| I _{FSM} | Surge non Repetitive Forward Current | t _p = 10ms | 7.5 | | Α | |
| | | $t_p = 1s$ | | 1.5 | | |
| P _{tot} | Power Dissipation | T _I = 25 °C | 33 | mW | | |
| T _{stg} T _j | Storage and Junction Temperature Range | - 65 t - 65 t | ပိုပို | | | |
| TL | Maximum Temperature for Soldering during | 26 | 60 | °C | | |

THERMAL RESISTANCE

| Symbol | Test Conditions | Value | Unit |
|----------------------|-----------------|-------|------|
| R _{th(j-l)} | Junction-leads | 300 | °C/W |

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ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

| Symbol | | Test Conditions | S | Min. | Тур. | Max. | Unit |
|------------------|-----------------------|-----------------------|-----------|------|------|------|------|
| V_{BR} | T _j = 25°C | $I_R = 10 \mu A$ | TMMBAT47 | 20 | | | V |
| | T _j = 25°C | $I_R = 25\mu A$ | TMMBAT48 | 40 | | | |
| V _F * | $T_j = 25^{\circ}C$ | $I_F = 0.1 \text{mA}$ | All Types | | | 0.25 | V |
| | T _j = 25°C | $I_F = 1mA$ | | | | 0.3 | |
| | T _j = 25°C | $I_F = 10mA$ | | | | 0.4 | |
| | T _j = 25°C | $I_F = 30mA$ | TMMBAT47 | | | 0.5 | |
| | T _j = 25°C | $I_F = 150 \text{mA}$ | | | | 0.8 | |
| | $T_j = 25^{\circ}C$ | $I_F = 300 \text{mA}$ | | | | 1 | |
| | T _j = 25°C | $I_F = 50 \text{mA}$ | TMMBAT48 | | | 0.5 | |
| | T _j = 25°C | $I_F = 200 \text{mA}$ | | | | 0.75 | |
| | T _j = 25°C | $I_F = 500 \text{mA}$ | | | | 0.9 | |
| I _R * | T _j = 25°C | V _R = 1.5V | All Types | | | 1 | μΑ |
| | T _j = 60°C | | | | | 10 | |
| | $T_j = 25^{\circ}C$ | V _R = 10V | TMMBAT47 | | | 4 | |
| | $T_j = 60^{\circ}C$ | | | | | 20 | |
| | T _j = 25°C | V _R = 20V | | | | 10 | |
| | T _j = 60°C | | | | | 30 | |
| | T _j = 25°C | V _R = 10V | TMMBAT48 | | | 2 | |
| | T _j = 60°C | | | | | 15 | _ |
| | $T_j = 25^{\circ}C$ | V _R = 20V | | | | 5 | |
| | $T_j = 60^{\circ}C$ | | | | | 25 | |
| | T _j = 25°C | V _R = 40V | | | | 25 | |
| | $T_j = 60^{\circ}C$ | | | | | 50 | |

DYNAMIC CHARACTERISTICS

| Symbol | Test Conditions | | | Min. | Тур. | Max. | Unit |
|-----------------|-----------------------|--|-------------------------|------|------|------|------|
| С | T _j = 25°C | $V_R = 0V$ | f = 1MHz | | 20 | | pF |
| | T _j = 25°C | $V_R = 1V$ | | | 12 | | |
| t _{rr} | T _j = 25°C | $I_F = 10 \text{mA}$ $V_R = 1 \text{V}$ $i_{rr} =$ | $1mA 	 R_L = 100\Omega$ | | 10 | | ns |

* Pulse test: $t_p \le 300 \mu s$ $\delta < 2\%$.

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Figure 1. Forward current versus forward voltage at different temperatures (typical values).

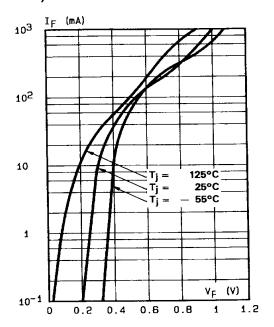


Figure 2. Forward current versus forward voltage (typical values).

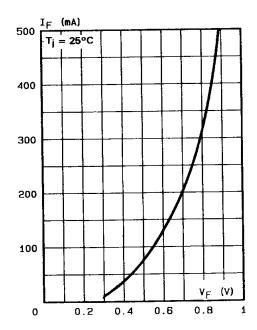


Figure 3. Reverse current versus junction temperature.

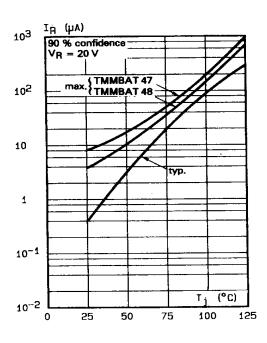


Figure 4. Reverse current versus continuous reverse voltage (typical values).

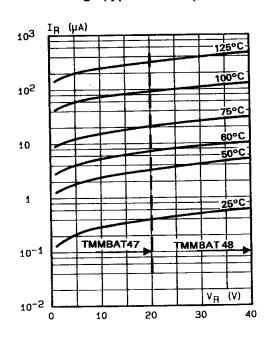
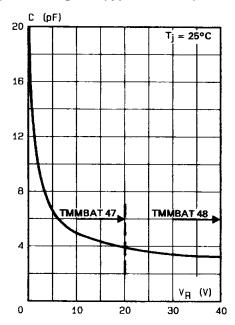




Figure 5. Capacitance C versus reverse applied voltage $V_{\mbox{\scriptsize R}}$ (typical values).

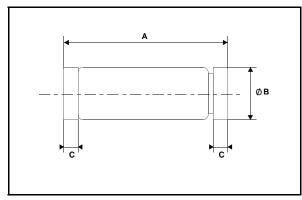


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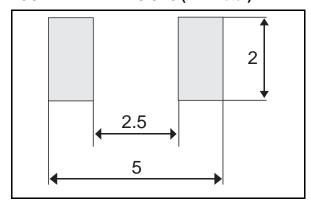
PACKAGE MECHANICAL DATA

MINIMELF Glass



| | DIMENSIONS | | | | | | |
|------|------------|-------------|------|-------|--------|-------|--|
| REF. | М | Millimeters | | | Inches | | |
| | Min. | Тур. | Max. | Min. | Тур. | Max. | |
| Α | 3.30 | 3.40 | 3.6 | 0.130 | 0.134 | 0.142 | |
| В | 1.59 | 1.60 | 1.62 | 0.063 | 0.063 | 0.064 | |
| С | 0.40 | 0.45 | 0.50 | 0.016 | 0.018 | 0.020 | |
| D | | 1.50 | | | 0.059 | | |

FOOT PRINT DIMENSIONS (Millimeter)



Marking: ring at cathode end. Weight: 0.05g

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